

# RJH60M2DPP-M0

600V - 12A - IGBT

Application: Inverter

R07DS0530EJ0300

Rev.3.00

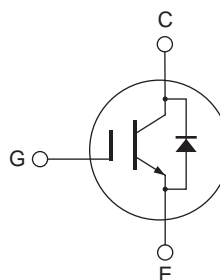
May 25, 2012

## Features

- Short circuit withstand time (8  $\mu$ s typ.)
- Low collector to emitter saturation voltage  
 $V_{CE(sat)} = 1.9$  V typ. (at  $I_C = 12$  A,  $V_{GE} = 15$  V,  $T_a = 25^\circ\text{C}$ )
- Built in fast recovery diode (85 ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching  
 $t_f = 45$  ns typ. (at  $V_{CC} = 300$  V,  $V_{GE} = 15$  V,  $I_C = 12$  A,  $R_g = 5$   $\Omega$ ,  $T_a = 25^\circ\text{C}$ , inductive load)

## Outline

RENESAS Package code: PRSS0003AF-A  
(Package name: TO-220FL)



1. Gate
2. Collector
3. Emitter

## Absolute Maximum Ratings

( $T_a = 25^\circ\text{C}$ )

Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		$V_{CES} / V_R$	600	V
Gate to emitter voltage		$V_{GES}$	$\pm 30$	V
Collector current	$T_c = 25^\circ\text{C}$	$I_C$	25	A
	$T_c = 100^\circ\text{C}$	$I_C$	12	A
Collector peak current		$i_{c(peak)}$ <sup>Note1</sup>	36	A
Collector to emitter diode forward current		$i_{DF}$	12	A
Collector to emitter diode forward peak current		$i_{DF(peak)}$ <sup>Note1</sup>	50	A
Collector dissipation		$P_C$ <sup>Note2</sup>	33.8	W
Junction to case thermal resistance (IGBT)		$\theta_{j-c}$ <sup>Note2</sup>	3.7	$^\circ\text{C} / \text{W}$
Junction to case thermal resistance (Diode)		$\theta_{j-cd}$ <sup>Note2</sup>	4.9	$^\circ\text{C} / \text{W}$
Junction temperature		$T_j$	150	$^\circ\text{C}$
Storage temperature		$T_{stg}$	-55 to +150	$^\circ\text{C}$

Notes: 1.  $PW \leq 10$   $\mu$ s, duty cycle  $\leq 1\%$

2. Value at  $T_c = 25^\circ\text{C}$

## Electrical Characteristics

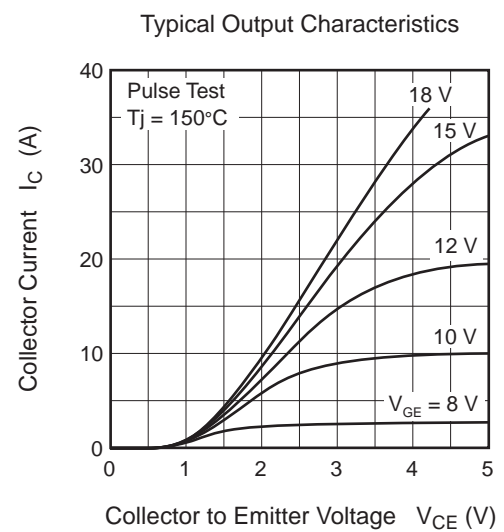
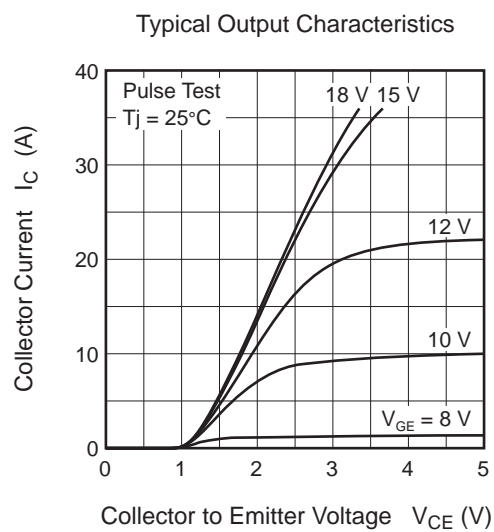
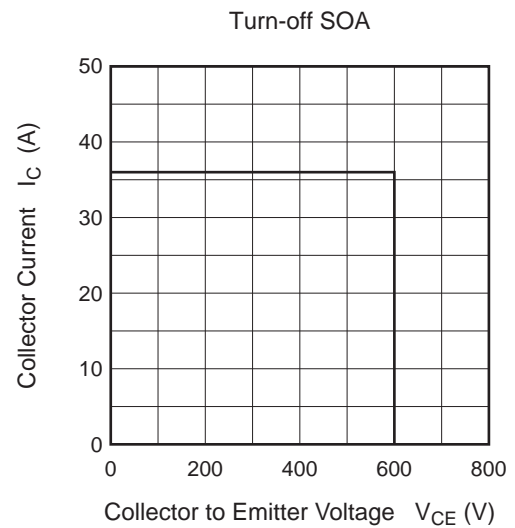
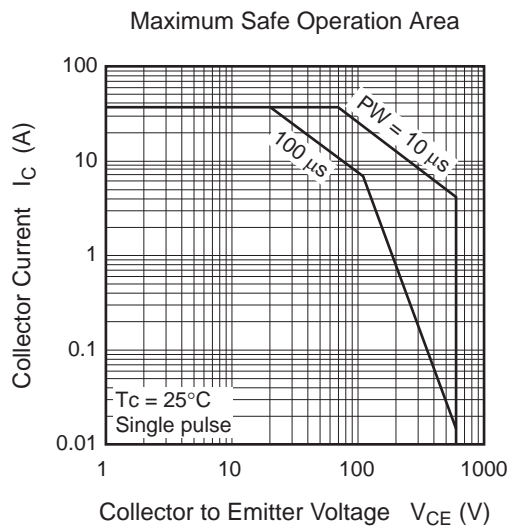
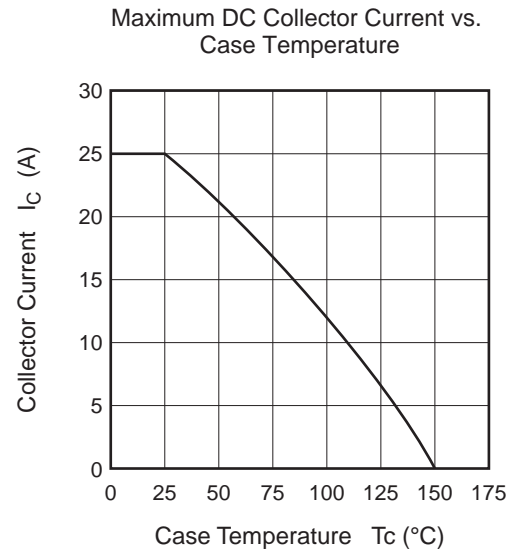
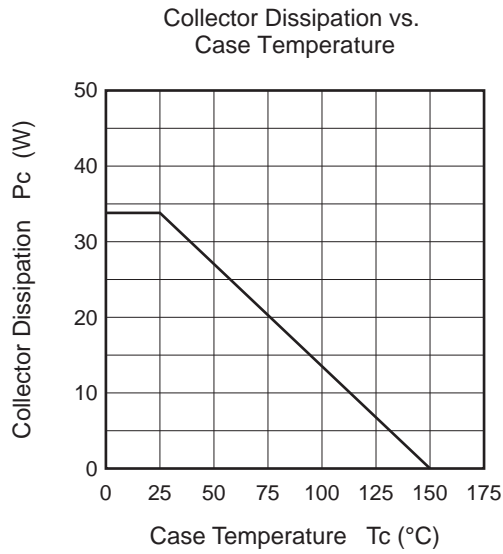
(Ta = 25°C)

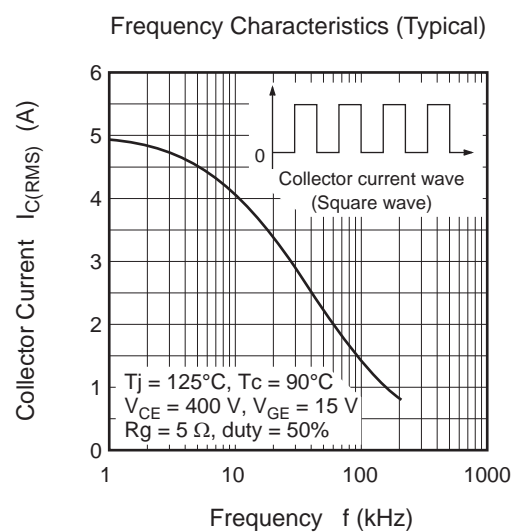
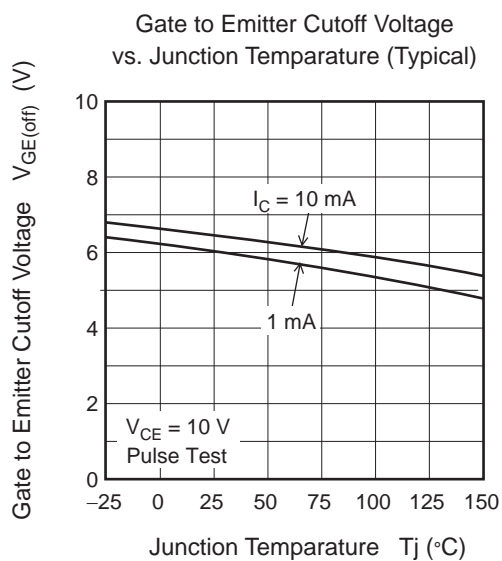
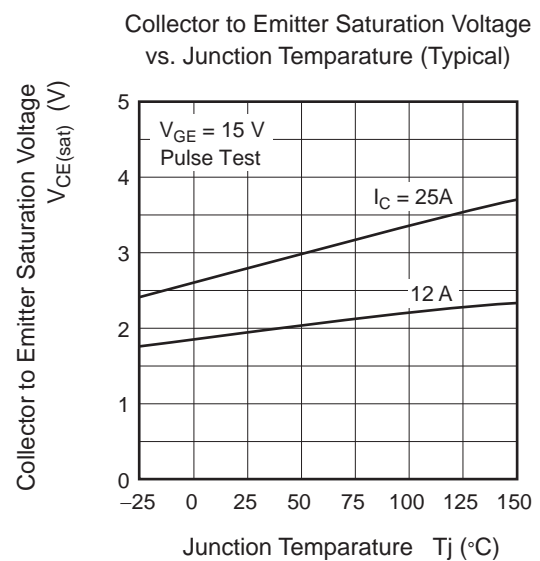
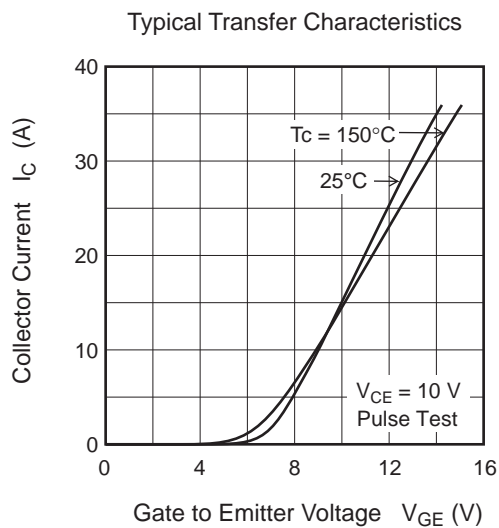
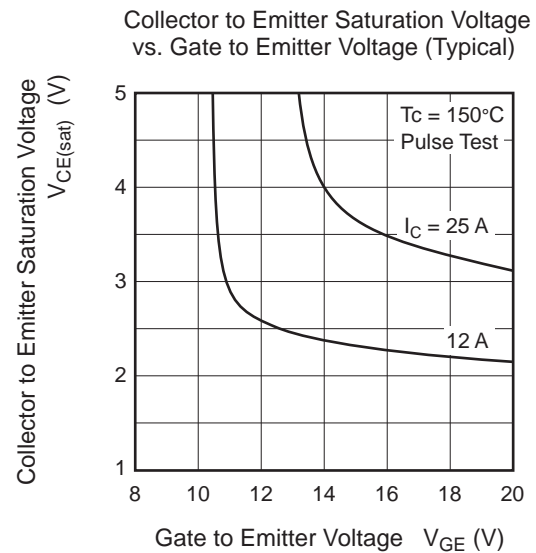
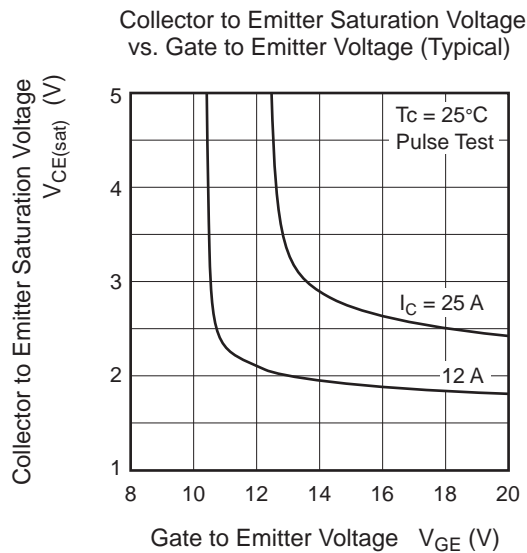
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Collector to emitter breakdown voltage	$V_{(BR)CES}$	600	—	—	V	$I_y = 10 \mu A, V_{GE} = 0$
Zero gate voltage collector current / Diode reverse current	$I_{CES} / I_R$	—	—	5	$\mu A$	$V_{CE} = 600 V, V_{GE} = 0$
Gate to emitter leak current	$I_{GES}$	—	—	$\pm 1$	$\mu A$	$V_{GE} = \pm 30 V, V_{CE} = 0$
Gate to emitter cutoff voltage	$V_{GE(off)}$	5	—	7	V	$V_{CE} = 10 V, I_C = 1 mA$
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	1.9	2.5	V	$I_C = 12 A, V_{GE} = 15 V$ <sup>Note3</sup>
	$V_{CE(sat)}$	—	2.8	—	V	$I_C = 25 A, V_{GE} = 15 V$ <sup>Note3</sup>
Input capacitance	$C_{ies}$	—	430	—	pF	$V_{CE} = 25 V$
Output capacitance	$C_{oes}$	—	40	—	pF	$V_{GE} = 0$
Reverse transfer capacitance	$C_{res}$	—	15	—	pF	$f = 1 MHz$
Total gate charge	$Q_g$	—	33	—	nC	$V_{GE} = 15 V$
Gate to emitter charge	$Q_{ge}$	—	5	—	nC	$V_{CE} = 300 V$
Gate to collector charge	$Q_{gc}$	—	19	—	nC	$I_C = 12 A$
Turn-on delay time	$t_{d(on)}$	—	32	—	ns	$V_{CC} = 300 V$ $V_{GE} = 15 V$ $I_C = 12 A$ $R_g = 5 \Omega$ Inductive load
Rise time	$t_r$	—	18	—	ns	
Turn-off delay time	$t_{d(off)}$	—	70	—	ns	
Fall time	$t_f$	—	45	—	ns	
Turn-on energy	$E_{on}$	—	0.18	—	mJ	
Turn-off energy	$E_{off}$	—	0.18	—	mJ	
Total switching energy	$E_{total}$	—	0.36	—	mJ	
Short circuit withstand time	$t_{sc}$	6	8	—	$\mu s$	$T_C = 100 ^\circ C$ $V_{CC} \leq 360 V, V_{GE} = 15 V$

FRD Forward voltage	$V_F$	—	1.2	1.6	V	$I_F = 12 A$ <sup>Note3</sup>
FRD reverse recovery time	$t_{rr}$	—	85	—	ns	$I_F = 12 A$ $di_F/dt = 100 A/\mu s$
FRD reverse recovery charge	$Q_{rr}$	—	0.14	—	$\mu C$	
FRD peak reverse recovery current	$I_{rr}$	—	4.2	—	A	

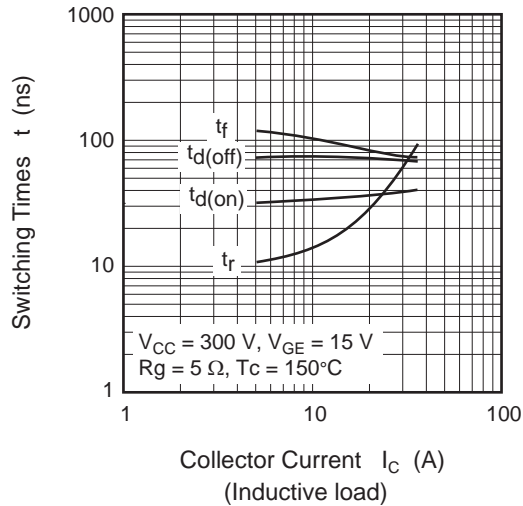
Notes: 3. Pulse test.

# Main Characteristics

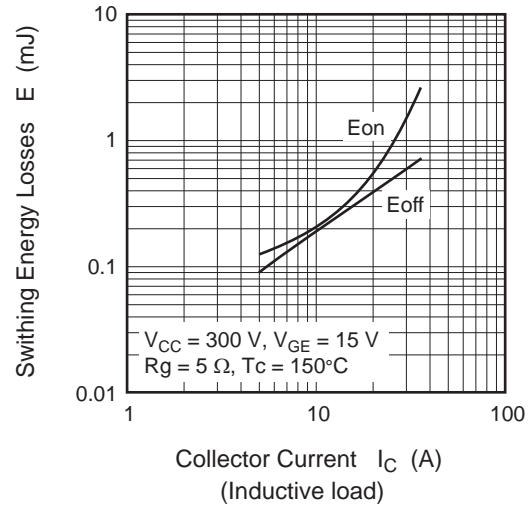




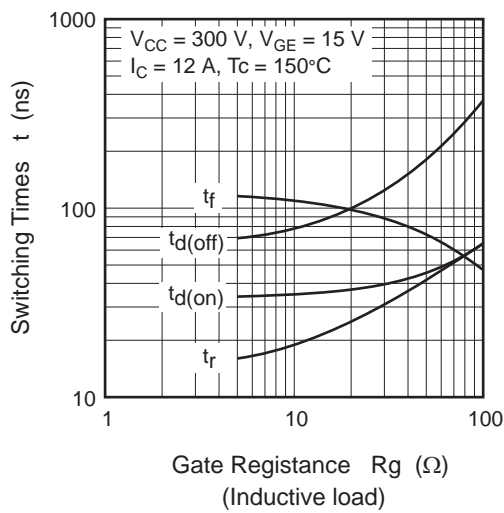
Switching Characteristics (Typical) (1)



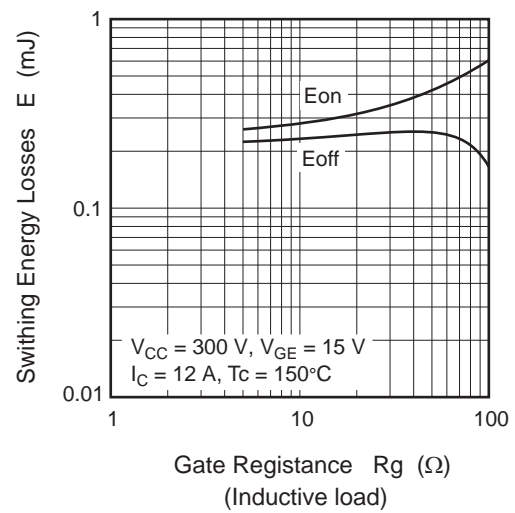
Switching Characteristics (Typical) (2)



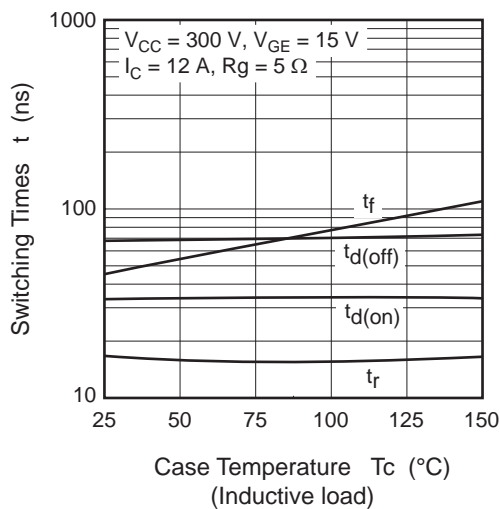
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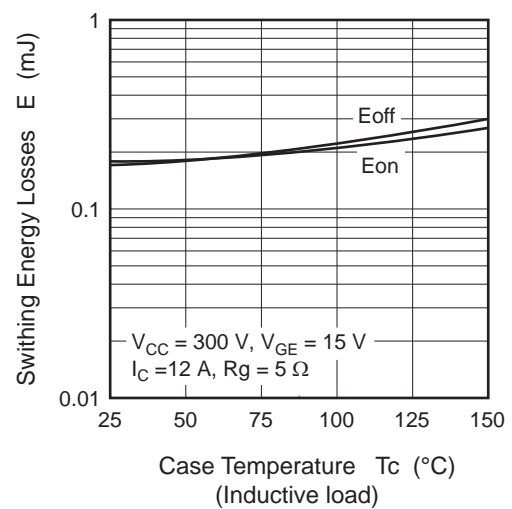
Switching Characteristics (Typical) (4)

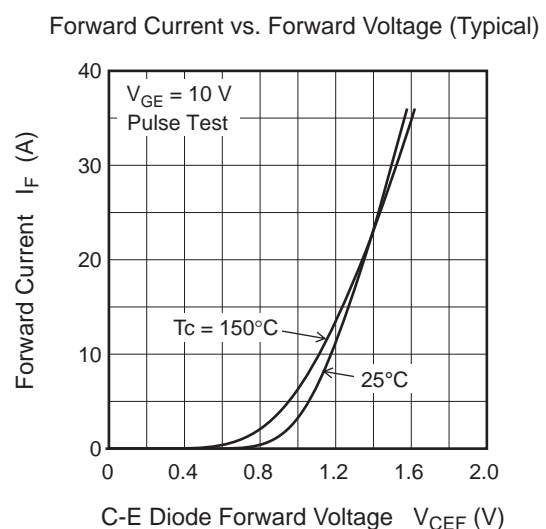
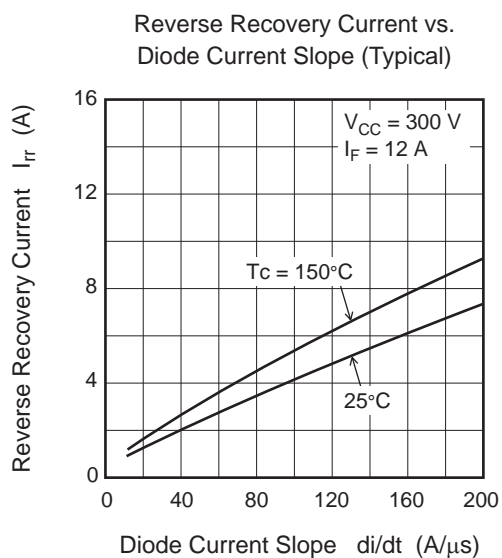
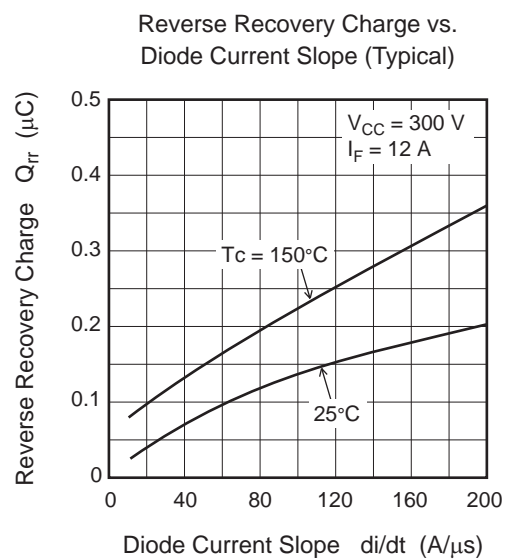
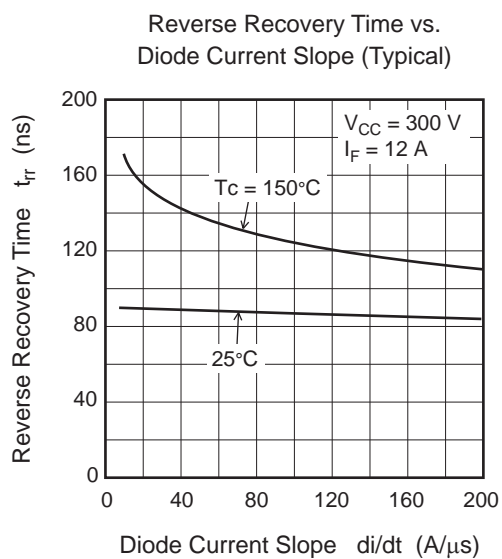
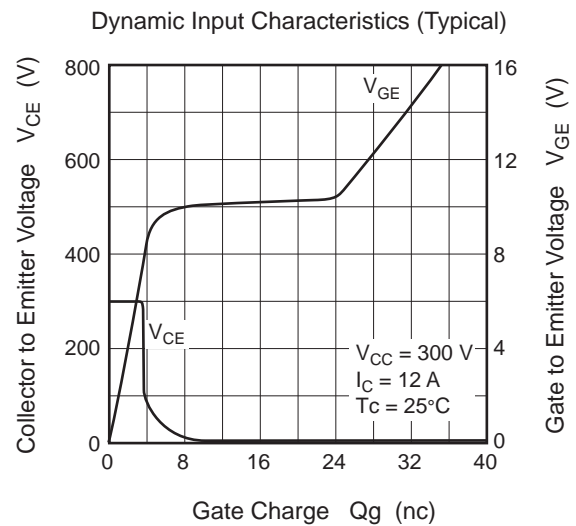
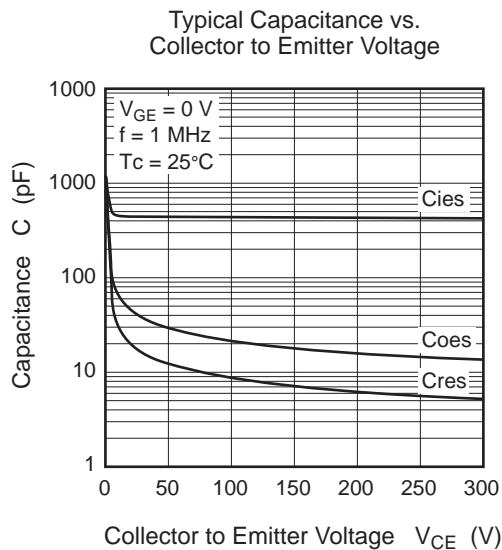


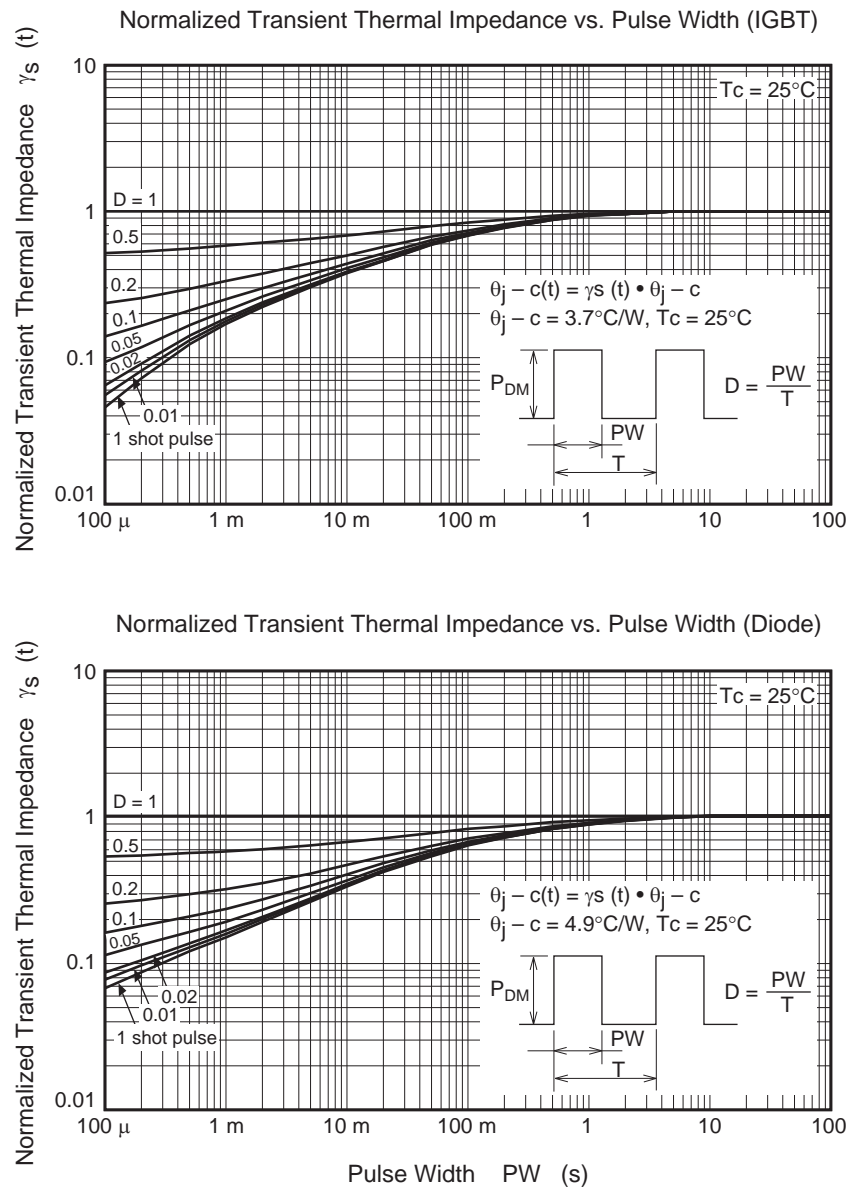
Switching Characteristics (Typical) (5)



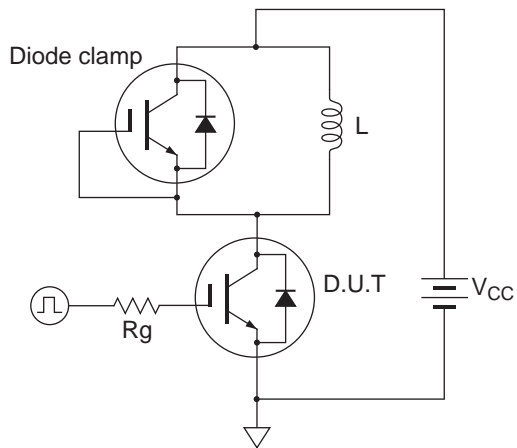
Switching Characteristics (Typical) (6)



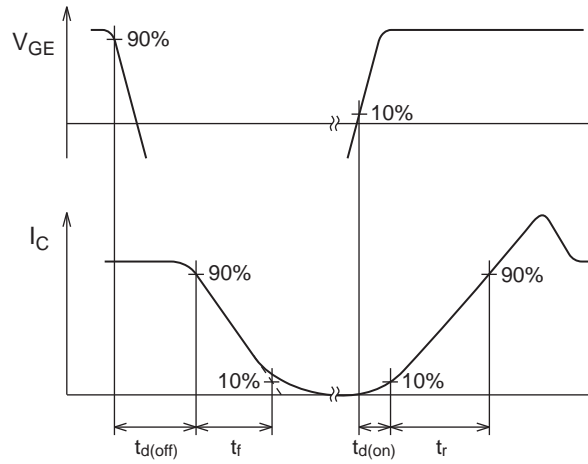




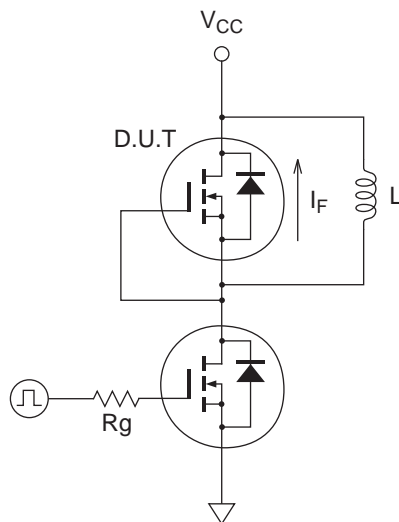
Switching Time Test Circuit



Waveform



Diode Reverse Recovery Time Test Circuit



Waveform





## Package Dimension

Package Name	JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]	Unit: mm
TO-220FL	—	PRSS0003AF-A	TO-220FL	1.5g	

The drawing shows the mechanical dimensions of the TO-220FL package. The top view shows a square body with a width of  $10.0 \pm 0.3$  mm and a height of  $15.0 \pm 0.3$  mm. The mounting tab has a width of  $6.5 \pm 0.3$  mm and a height of  $3.0 \pm 0.3$  mm. The central hole has a diameter of  $\phi 3.2 \pm 0.2$  mm. The side view shows a total height of  $12.5 \pm 0.5$  mm, with a mounting tab height of  $3.6 \pm 0.3$  mm. The lead height is  $2.8 \pm 0.2$  mm. The lead width at the base is  $0.40 \pm 0.15$  mm. The lead thickness is  $0.75 \pm 0.15$  mm. The lead width at the mounting tab is  $1.15 \pm 0.2$  mm. The lead width at the base is  $2.54 \pm 0.25$  mm. The detail view shows a lead width of  $2.6 \pm 0.2$  mm and a lead thickness of  $4.5 \pm 0.2$  mm.

## Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJH60M2DPP-M0#T2	600 pcs	Box (Tube)

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